



DMNH6011LK3

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
55V	$12m\Omega @ V_{GS} = 10V$	80A
557	$18m\Omega @ V_{GS} = 4.5V$	65A

# Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Power Supplies
- Motor Control
- DC-DC Converters

## 55V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

## Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures more Reliable and Robust End Application
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Data Sheet (<u>DMNH6011LK3Q</u>)

# **Mechanical Data**

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Top View

Pin Out Top View

G

Equivalent Circuit

# Ordering Information (Note 4)

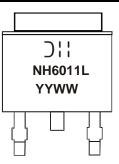
	Part Number	Case	Packaging		
DMNH6011LK3-13		TO252 (DPAK)	2,500/Tape & Reel		
Notes:	lotes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.				

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



) | | =Manufacturer's Marking
NH6011L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	55	V	
Gate-Source Voltage	V <sub>GSS</sub>	±12	V	
Continuous Drain Current (Note 7), $V_{GS} = 10V$	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I <sub>D</sub>	80 50	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	180	A	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	2.8	A	
Avalanche Current, L = 0.1mH (Note 8)	I <sub>AS</sub>	54	A	
Avalanche Energy, L = 0.1mH (Note 8)		E <sub>AS</sub>	147	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	80	°C/W
Total Power Dissipation (Note 6)		PD	3.0	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		R <sub>0JA</sub>	42	°C/W
Thermal Resistance, Junction to Case (Note 7)		R <sub>θJC</sub>	1.1	0.700
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	Cymbol	WIIII	тур	Max	Onic		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	55	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current, $T_J = +25^{\circ}C$	IDSS	_	_	1	μA	$V_{DS} = 55V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	-000						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	2	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	8.3	12		$V_{GS} = 10V, I_D = 25A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	9.0	18	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 25A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.7A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		3,077	—	pF		
Output Capacitance	Coss	_	331	—	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	127	—	pF		
Gate Resistance	Rg		1.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		23.4	—	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	49.1	—	nC		
Gate-Source Charge	Q <sub>gs</sub>		5.3	—	nC	$V_{DS} = 30V, I_D = 25A$	
Gate-Drain Charge	Q <sub>gd</sub>		9.6	—	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>		5.9	—	ns		
Turn-On Rise Time	t <sub>R</sub>		8.7	—	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		28.2	—	ns	$R_{G} = 3\Omega, I_{D} = 25A$	
Turn-Off Fall Time	tF		10.2	—	ns		
Body Diode Reverse Recovery Time	t <sub>RR</sub>		30.1	—	ns	I <sub>F</sub> = 25A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	25.7	—	nC	I <sub>F</sub> = 25A, di/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

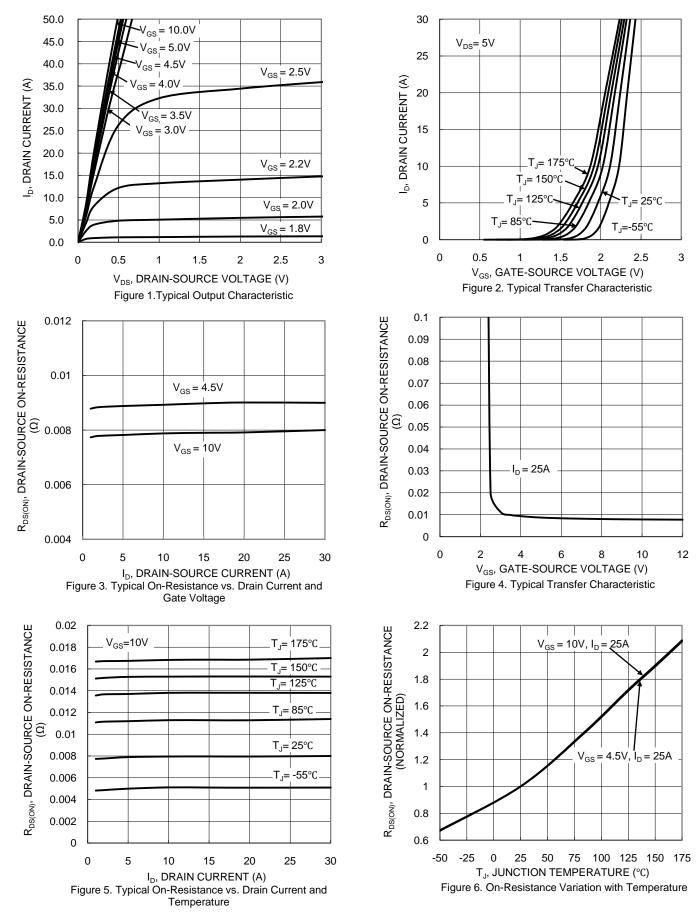
8. IAS and EAS ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.

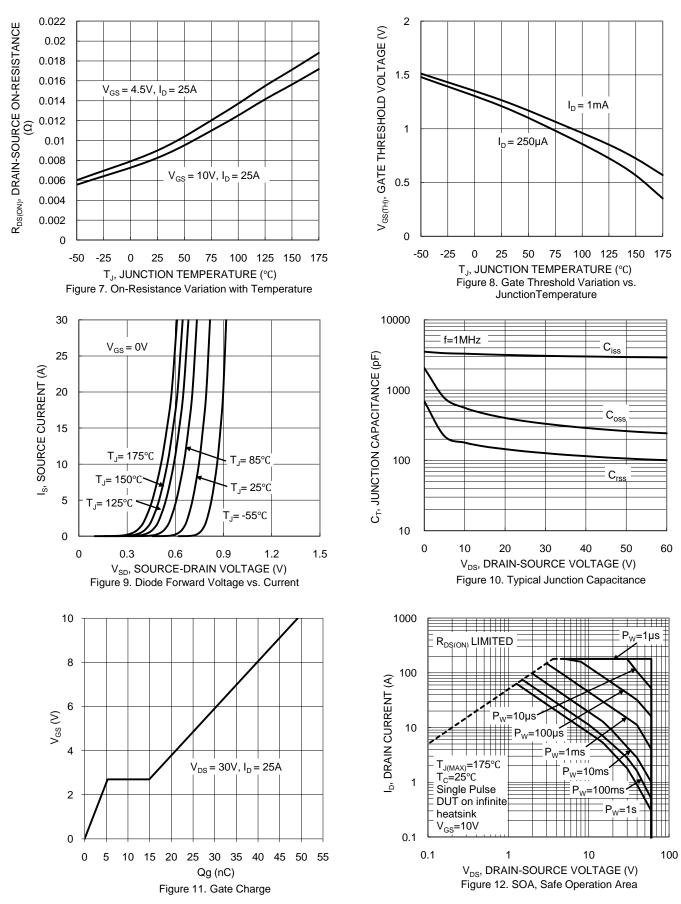


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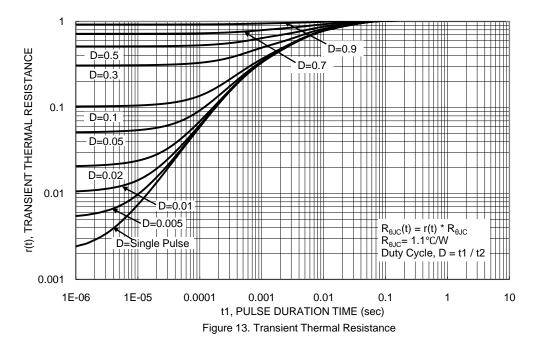




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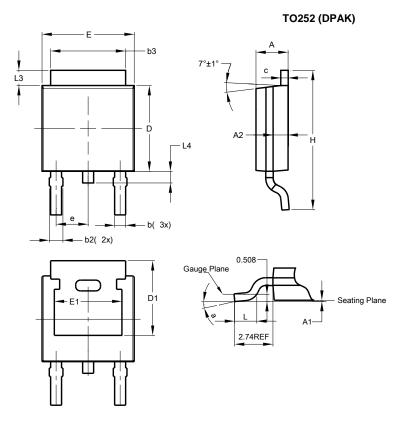






# **Package Outline Dimensions**

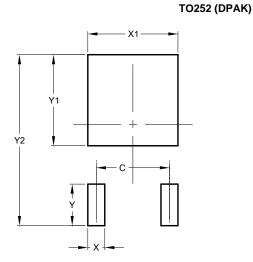
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)						
Dim	Min	Max Typ				
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21					
e	-	- 2.28				
Е	6.45	6.70	6.58			
E1	4.32	-	-			
H	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			



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